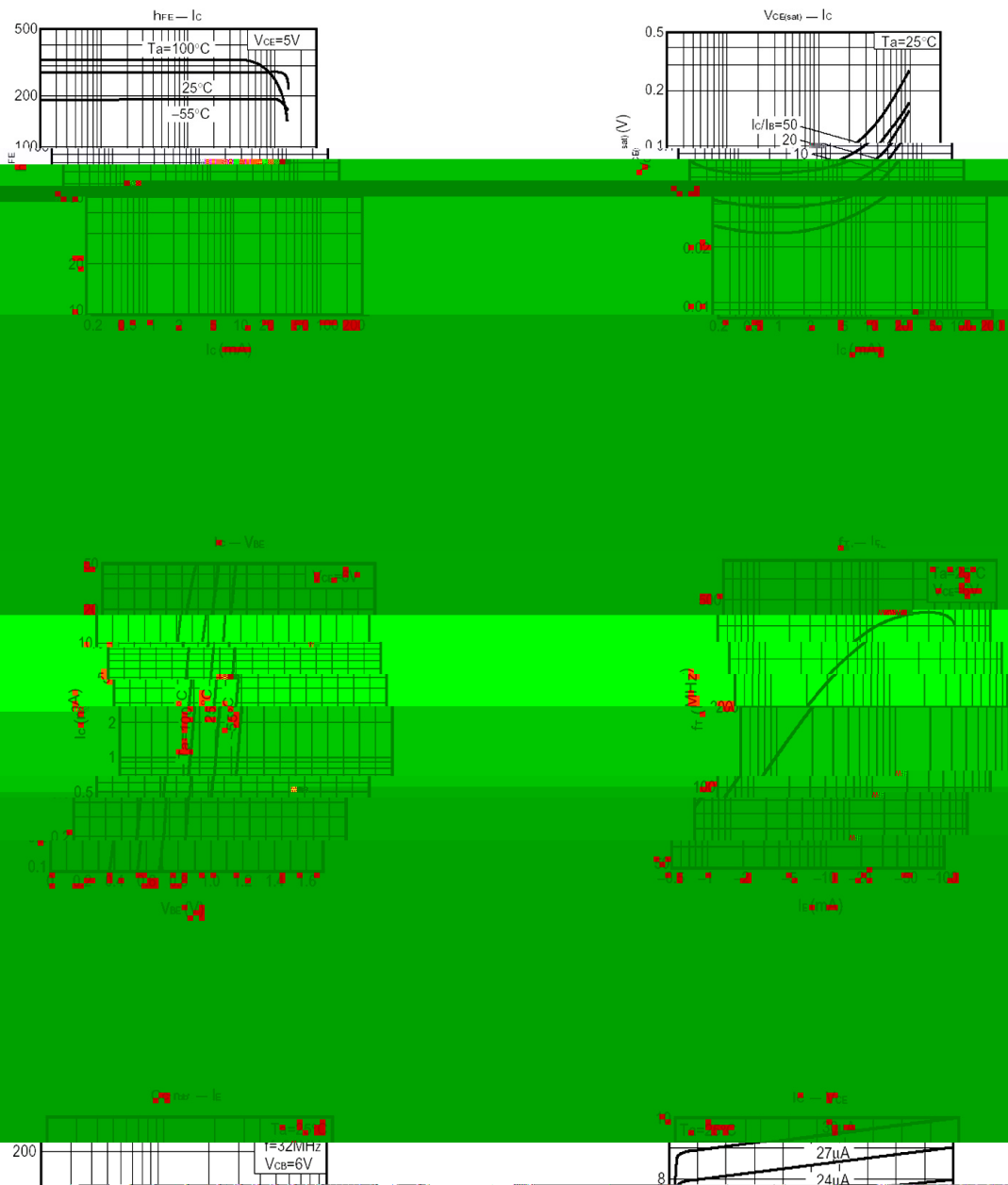


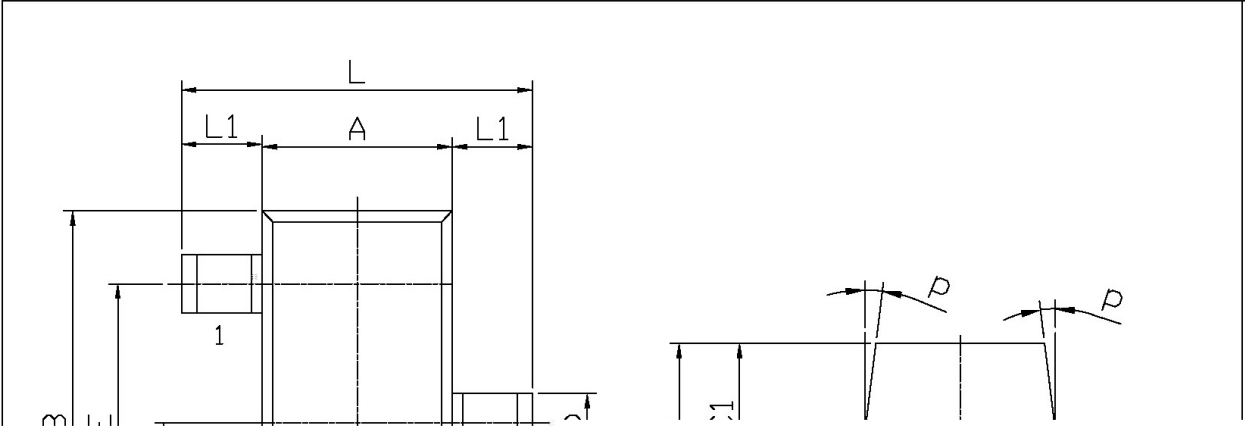
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	50	V
Emitter to Base Voltage	V_{EBO}	7.0	V
Collector Current	I_C	150	mA
Collector Power Dissipation	P_C	200	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55~150	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- Base Breakdown Voltage	V_{CBO}	$I_C=50\mu A$	60			V
Collector-Emitter Breakdown Voltage	V_{CEO}	$I_C=1.0mA$	50			V
Emitter-Base Breakdown Voltage	V_{EBO}	$I_E=50\mu A$	7.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=60V$			0.1	μA
Emitter Base Cut-Off Current	I_{EBO}	$V_{EB}=7.0V$			0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=6.0V$ $I_C=1.0mA$	120		560	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=50mA$ $I_B=5.0mA$			0.4	V
Transition Frequency	f_T	$V_{CE}=12V$ $f=100MHz$ $I_E=-2.0mA$		180		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=12V$ $f=1.0MHz$ $I_E=0$		2.0	3.5	pF

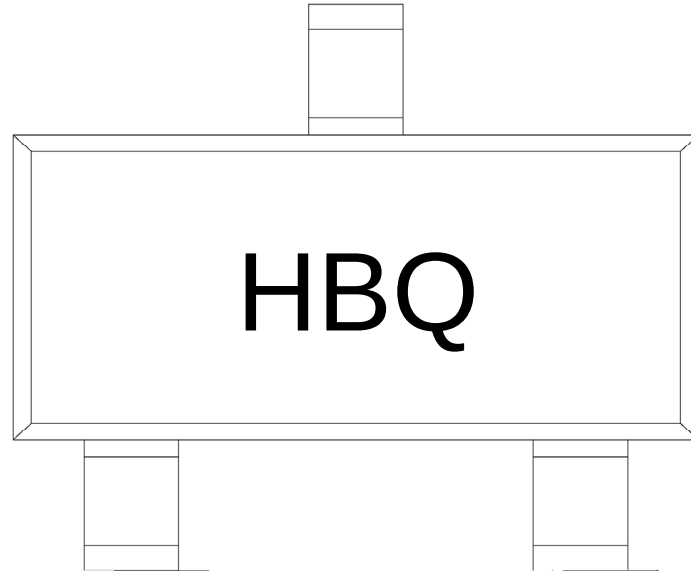


SOT-23

单位：mm



	DIM			UNIT	
	MIN	MAX		MIN	MAX
L	2.2	2.7	C	1.30Max	
L1	0.45	0.65	C1	0.90	1.20
A	1.15	1.50	∠	0.05	0.20
B	2.70	3.10	K	0	0.10
E	1.70	2.10	M	0.20MIN	
E1	0.85	1.05	φ	7°	
b	0.35	0.55			



H

B

Q h_{FE}

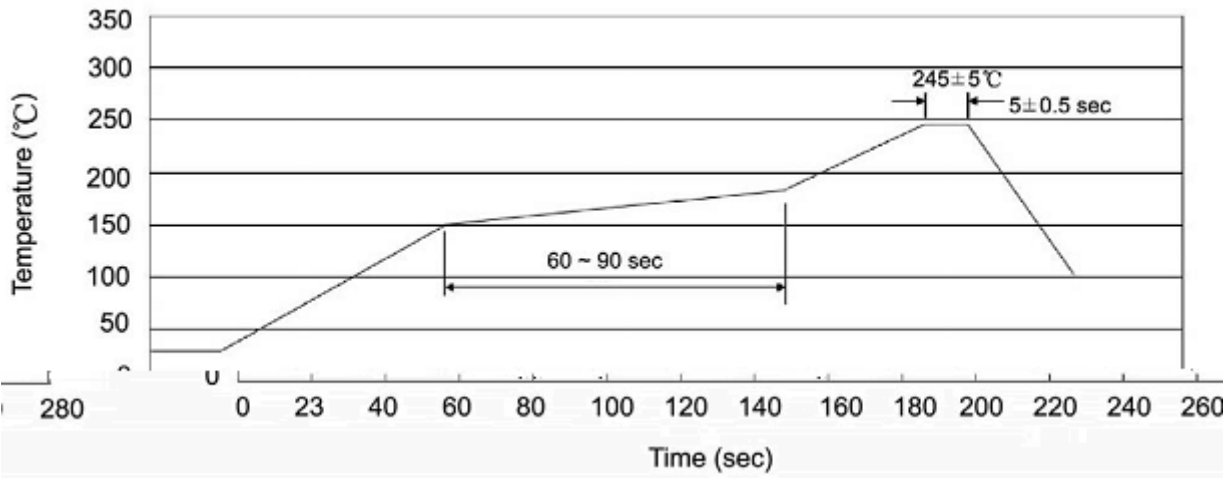
Note:

H Company Code

B Product Type Code

Q h_{FE} Classifications Symbol

Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- 1

25 150

60 90sec;

1.Preheating:25~150 , Time:60~90sec.
- 2

245±5

5±0.5sec;

2.Peak Temp.:245±5 , Duration:5±0.5sec.
- 3

2 10 /sec.

3. Cooling Speed: 2~10 /sec.

260±5

10±1 sec.

Temp.:260±5

Time:10±1 sec

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-23	3,000	10	30,000	6	180,000	7" x8	180×120×180	390×385×205